



8.13: Photoelectric Effect Experiment Vinh Q. Tran

Table of Contents

- Overview of the photoelectric effect
- Experiment apparatus
- Data collection
- Cutoff voltages measurement
- Plank constant & work function

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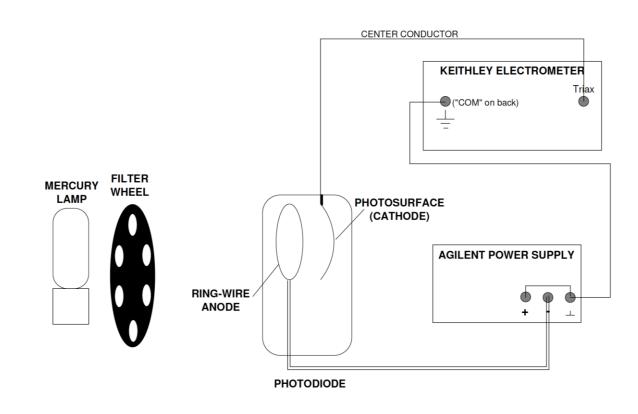
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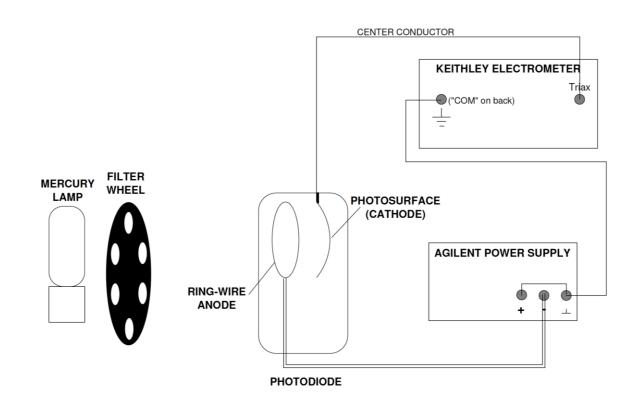
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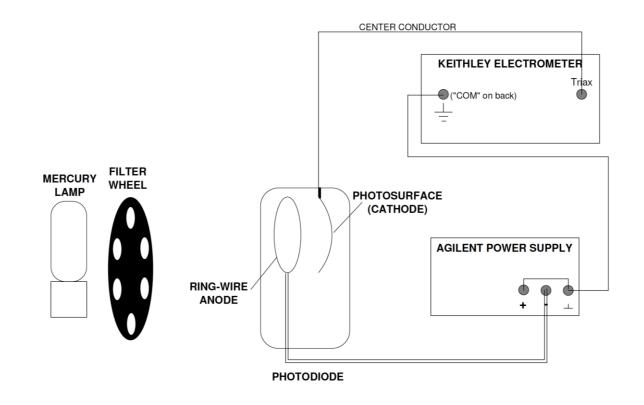
• In this experiment, we look at $K = eV_{\rm cutoff}$, with $V_{\rm cutoff}$ as the (retarded) cutoff voltage.



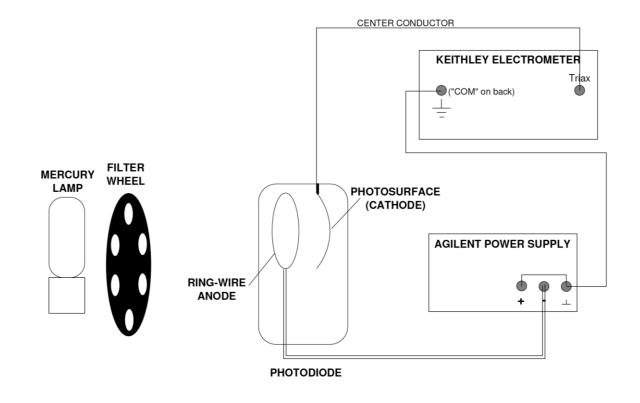
• Measurements are made with the wavelengths of $\lambda = 365.0, 404.7, 435.8$, and 546.2 nm, isolated using the filter wheel.



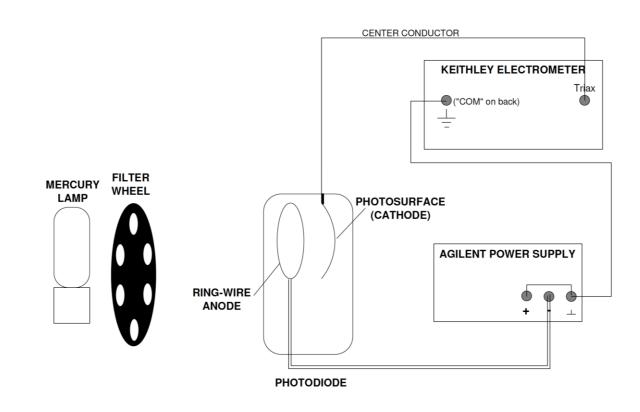
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- All equipment are properly grounded and special care has been paid for geometrical alignment.



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- In response to the high rate of fluctuation in the photoelectric current, for each voltage, we record (on average) 12 consecutive current values I_i .
- For each voltage, we measure the photoelectric current, with the lamp blocked and unblock, surveying and removing background signals.



The current and its uncertainties are reduced following

$$-2\log(\mathcal{L}) = N.\log(2\pi\sigma_I^2) + \sum_{i} \left(\frac{I_i - \mu_I}{\sigma_I}\right)^2$$

$$\mu_I, \sigma_I = \arg\min_{\mu_I, \sigma_I} -2\log(\mathcal{L})$$

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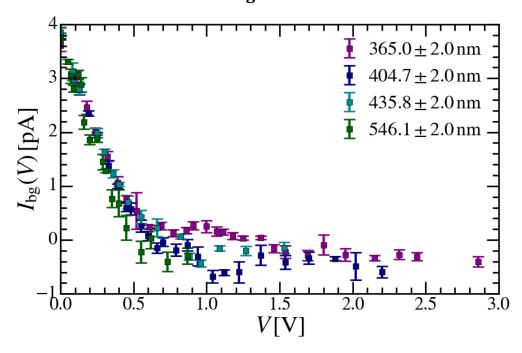
The photoelectric current is then obtained

$$I_{\rm pe} = I_{\rm total} - I_{\rm bg}$$

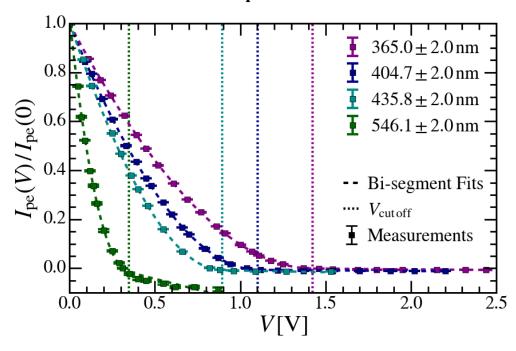
with I_{bg} and I_{total} as the measured currents when the lamp is blocked and unblocked.

16

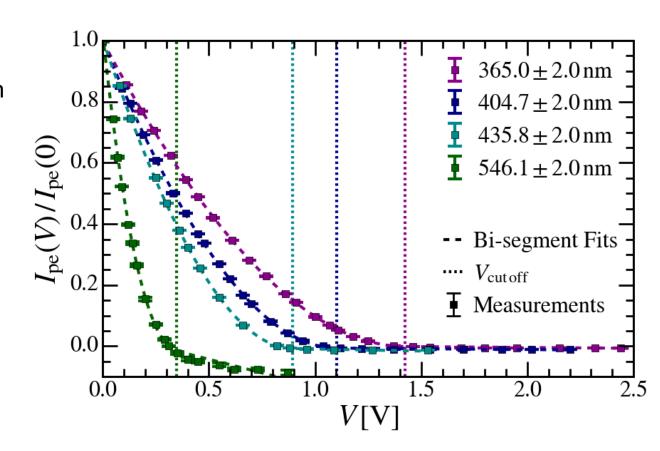
Background current I_{bg}



Photoelectric current I_{pe}



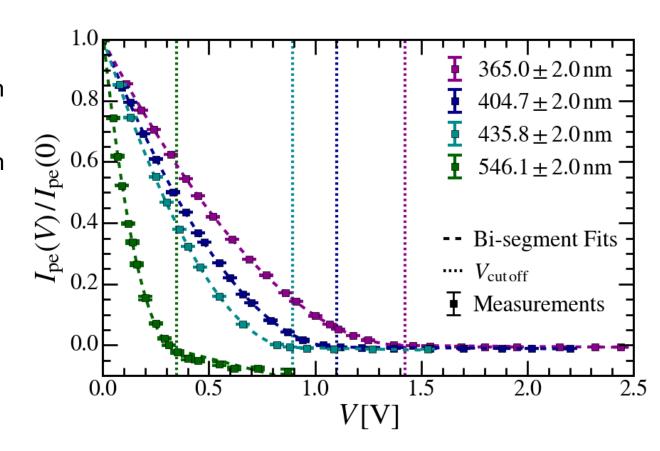
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- Polynomial order is determined by the Chow test, with the f-statistics

$$F_{n,n'} = \frac{(\chi_{n'}^2 - \chi_n^2)/(n - n')}{\chi_n^2/(N - n)}$$

Between polynomials of order n and n' < n, and comparing $F_{n,n'}$ to $F_{\alpha=0.05}$.

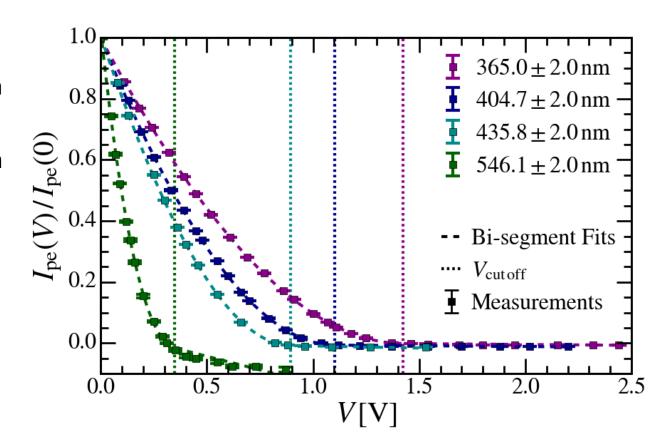


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• n = 3 provides the best results for our data.

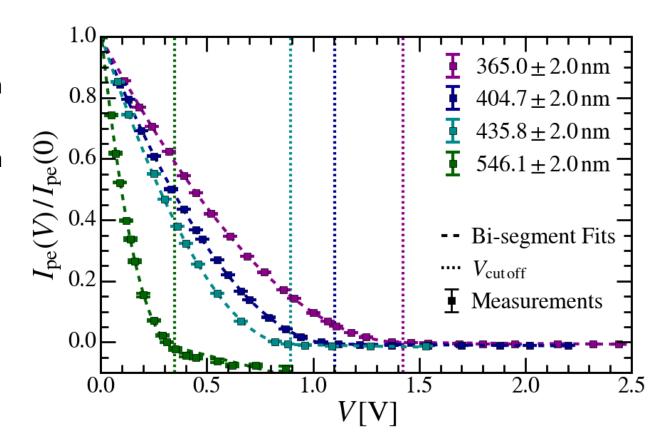


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Between polynomials of order n and n' < n, and comparing $F_{n.n'}$ to $F_{\alpha=0.05}$.

- n = 3 provides the best results for our data.
- Using a bi-segment fit (polynomial for $V < V_{\rm cutoff}$, and linear for $V \ge V_{\rm cutoff}$, with smooth transitioning) to determine $V_{\rm cutoff}$.



• Uncertainties are propagated from the uncertainties in voltage as the uncertainties in current are insignificant.

λ	$V_{ m cut\ off}$	$\sim I_{ m pe}(V_{ m cutoff})$
[nm]	[V]	[pA]
365.0 ± 2.0	1.425 ± 0.010	-1.2
404.7 ± 2.0	1.104 ± 0.014	-2.2
435.8 ± 2.0	0.892 ± 0.015	-4.2
546.1 ± 2.0	0.366 ± 0.059	-0.8

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- 10000 Monte Carlo samples of voltages are obtained, each is fitted to obtain a value of V_{cutoff}. The distribution of V_{cutoff} determine the uncertainty.
- The systematic error of the cutoff voltage measurements is taken as the typical deviation of $V_{\rm cutoff}$ from $V_{I_{\rm pe}=0}$, which is ~ 0.04 V.

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• Find the optimized values of h and ϕ using the prior

$$e\hat{V}_{\text{cutoff}}(v) = hv - \phi$$

and the negative log likelihood

$$-2\log(\mathcal{L}) = \sum_{i} \frac{\left(V_{\text{cutoff},i} - \hat{V}_{\text{cutoff}}(\nu_{i})\right)^{2}}{\sigma_{V_{\text{cutoff},i}}^{2} + \left(\frac{\partial \hat{V}_{\text{cutoff}}(\nu_{i})}{\partial \nu}\right)^{2} \sigma_{\nu_{i}}^{2}}$$

26

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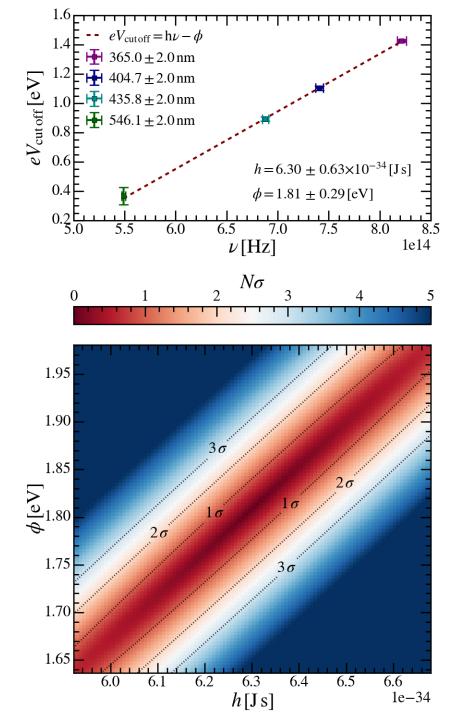
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 The N-sigma gaussian-equivalent uncertainties are obtained using the covariance matrix C

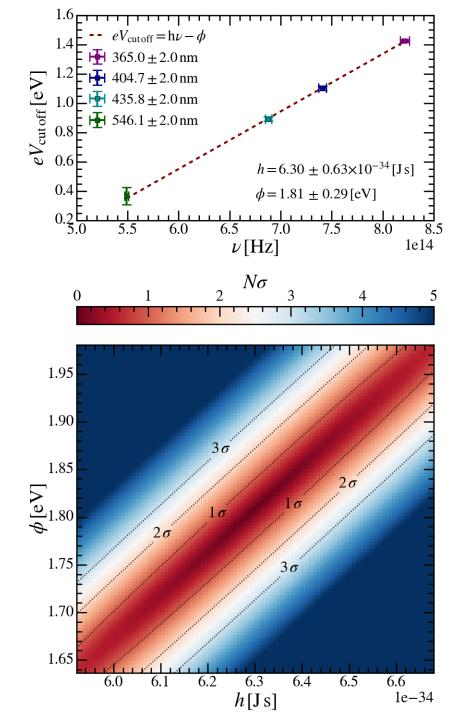
$$(C)_{\theta,\theta'}^{-1} \approx -\frac{\partial^2 \log(\mathcal{L})}{\partial \theta \partial \theta'}$$

$$N^2 = \sum_{\theta,\theta'} (\theta - \theta_0) (C)_{\theta,\theta'}^{-1} (\theta' - \theta'_0)$$

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- Nevertheless, the obtained value of h remains close to the literature's $h = 6.63 \times 10^{-34}$ J s.
- Systematic error is propagated from the systematic error of the cutoff voltages and is of the order of $\sim 5\%$ (~ 0.32 J s).

